## 74LVC1G10-Q100

Single 3-input NAND gate Rev. 5 — 14 August 2023

### 1. General description

The 74LVC1G10-Q100 provides a low-power, low-voltage single 3-input NAND gate.

The inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall time.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
   Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- ±24 mA output drive (V<sub>CC</sub> = 3.0 V)
- CMOS low power dissipation
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

### 3. Ordering information

#### Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LVC1G10GW-Q100	-40 °C to +125 °C		plastic thin shrink small outline package; 6 leads; body width 1.25 mm	<u>SOT363-2</u>

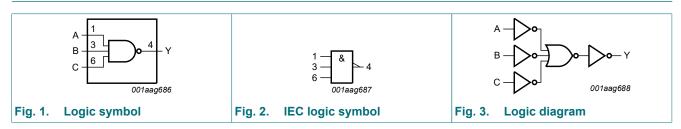
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### 4. Marking

Table 2. Marking	
Type number	Marking code [1]
74LVC1G10GW-Q100	YM

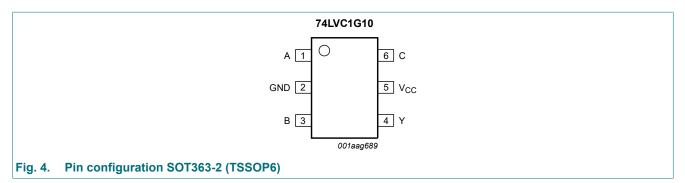
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

### 5. Functional diagram



### 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

#### Table 3. Pin description

Symbol	Pin	Description
A	1	data input
GND	2	ground (0 V)
В	3	data input
Y	4	data output
V <sub>CC</sub>	5	supply voltage
С	6	data input

### 7. Functional description

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input	Output		
Α	В	C	Y
Н	Н	Н	L
L	Х	Х	Н
Х	L	Х	Н
Х	Х	L	Н

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>CC</sub>	supply voltage			-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>1</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V		-	±50	mA
Vo	output voltage	Active mode	[1]	-0.5	V <sub>CC</sub> + 0.5	V
		Power-down mode; $V_{CC}$ = 0 V	[1]	-0.5	+6.5	V
I <sub>O</sub>	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±50	mA
I <sub>CC</sub>	supply current			-	100	mA
I <sub>GND</sub>	ground current			-100	-	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	250	mW
T <sub>stg</sub>	storage temperature			-65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT363-2 (TSSOP6) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

### 9. Recommended operating conditions

#### Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>CC</sub>	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V <sub>CC</sub>	V
		Power-down mode; $V_{CC}$ = 0 V	0	-	5.5	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V	-	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V	-	-	10	ns/V

### **10. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 '	-40 °C to +85 °C			-40 °C to +125 °C	
			Min	Typ [1]	Мах	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65V <sub>CC</sub>	-	-	0.65V <sub>CC</sub>	-	V
	input`voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7V <sub>CC</sub>	-	-	0.7V <sub>CC</sub>	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35V <sub>CC</sub>	-	0.35V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3V <sub>CC</sub>	-	0.3V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
	voltage	I <sub>O</sub> = -100 μA; V <sub>CC</sub> = 1.65 V to 5.5 V	V <sub>CC</sub> - 0.1	-	-	V <sub>CC</sub> - 0.1	-	V
		I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V	1.2	-	-	0.95	-	V
		I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	1.7	-	V
		I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V	2.2	-	-	1.9	-	V
		I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V	2.3	-	-	2.0	-	V
		I <sub>O</sub> = -32 mA; V <sub>CC</sub> = 4.5 V	3.8	-	-	3.4	-	V
V <sub>OL</sub>	LOW-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
	voltage	I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 1.65 V to 5.5 V	-	-	0.10	-	0.10	V
		I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V	-	-	0.45	-	0.70	V
		I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V	-	-	0.30	-	0.45	V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V	-	-	0.40	-	0.60	V
		I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V	-	-	0.55	-	0.80	V
		I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V	-	-	0.55	-	0.80	V
I	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	±0.1	±1	-	±1	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 5.5 V; $V_{CC}$ = 0 V	-	±0.1	±2	-	±2	μA
I <sub>CC</sub>	supply current	$V_{I} = 5.5 V \text{ or GND; } I_{O} = 0 \text{ A;}$ $V_{CC} = 1.65 V \text{ to } 5.5 V$	-	0.1	4	-	4	μA
Δl <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A;$ $V_{CC} = 2.3 V to 5.5 V; per pin$	-	5	500	-	500	μA
CI	input capacitance	$V_{CC}$ = 3.3 V; $V_{I}$ = GND to $V_{CC}$	-	3	-	-	-	pF

[1] All typical values are measured at  $T_{amb}$  = 25 °C.

### **11. Dynamic characteristics**

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 6.

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ [1]	Max	Min	Мах	
t <sub>pd</sub>	propagation delay	A, B and C to Y; see Fig. 5 [2]						
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.5	4.7	18.0	1.5	21.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.0	3.0	6.5	1.0	7.8	ns
		V <sub>CC</sub> = 2.7 V	1.0	3.0	6.0	1.0	7.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.6	5.0	1.0	6.2	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.0	1.9	3.6	1.0	4.4	ns
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$ [3]	-	12	-	-	-	pF

Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively. [1]

[2]

 $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in µW). [3]

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

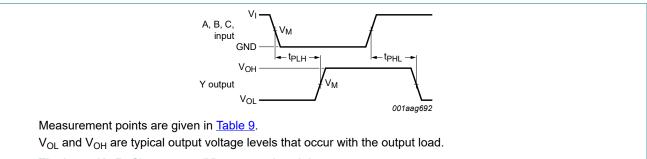
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

### 11.1. Waveforms and test circuit



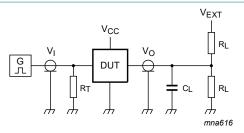
#### The input (A, B, C) to output (Y) propagation delays Fig. 5.

#### Table 9. Measurement points

Supply voltage	Input	Output
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>
1.65 V to 1.95 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.3 V to 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>

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Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

 $C_L$  = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator;

 $V_{EXT}$  = External voltage for measuring switching times.

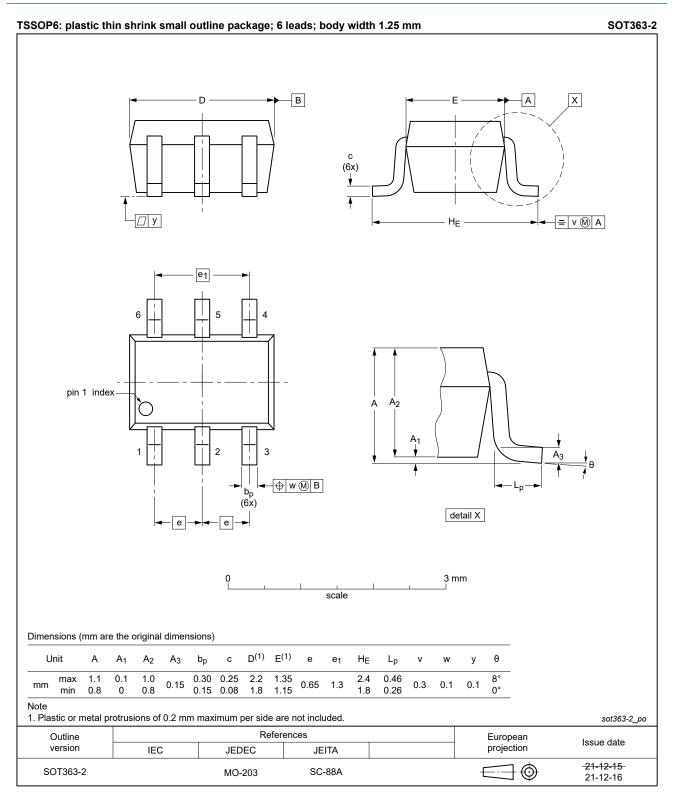
#### Fig. 6. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>
V <sub>cc</sub>	VI	t <sub>r</sub> = t <sub>f</sub>	CL	RL	t <sub>PLH</sub> , t <sub>PHL</sub>
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	500 Ω	open

#### Single 3-input NAND gate

### 12. Package outline



#### Fig. 7. Package outline SOT363-2 (TSSOP6)

### 13. Abbreviations

Table 11. Abbreviations	Table 11. Abbreviations				
Acronym	Description				
CDM	Charged Device Model				
CMOS	Complementary Metal Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
TTL	Transistor-Transistor Logic				

### 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G10_Q100 v.5	20230814	Product data sheet	-	74LVC1G10_Q100 v.4
Modifications:	• <u>Section 2</u> : E	SD specification updated a	according to the la	atest JEDEC standard.
74LVC1G10_Q100 v.4	20211115	Product data sheet	-	74LVC1G10_Q100 v.3
Modifications:	• SOT363 (S	C-88) package changed to	SOT363-2 (SC-8	8) package.
74LVC1G10_Q100 v.3	20210602	Product data sheet	-	74LVC1G10_Q100 v.2
Modifications:	guidelines o Legal texts	of this data sheet has beer of Nexperia. have been adapted to the i Derating values for P <sub>tot</sub> tota	new company nar	ne where appropriate.
74LVC1G10_Q100 v.2	20161207	Product data sheet	-	74LVC1G10_Q100 v.1
Modifications:	• <u>Table 7</u> : The	e maximum limits for leaka	ge current and su	pply current have changed
74LVC1G10 Q100 v.1	20161101	Product data sheet	-	-

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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